

## Fast CMOS 16-Bit Registered Transceivers

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### Product Features:

#### Common Features:

- PI74FCT16952T and PI74FCT162952T have high current drive and four speed grades.
  - "A" speeds at 10.0 ns max.
  - "B" speeds at 7.5 ns max.
  - "C" speeds at 6.3 ns max.
  - "D" speeds at 4.4 ns max.
  - "E" speeds at 3.7 ns max.
- V<sub>CC</sub> = 5 V ±10%
- Hysteresis on all inputs
- Packaged in 56-pin plastic TSSOP and SSOP

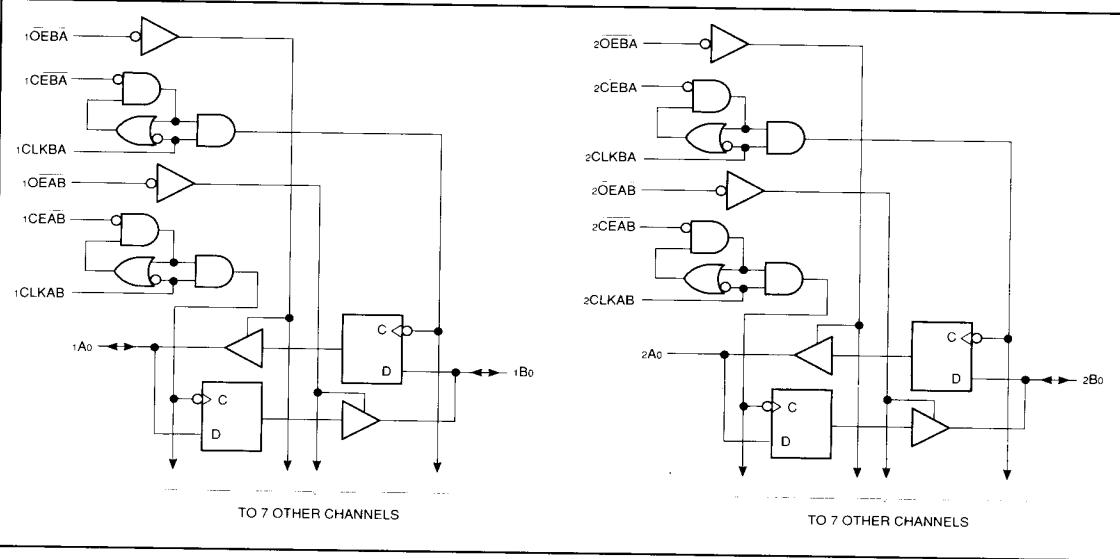
#### PI74FCT16952T Features:

- High output drive: I<sub>OH</sub> = +32 mA; I<sub>OL</sub> = 64 mA
- Power off disable outputs permit "live insertion"
- Typical VOLP (Output Ground Bounce) < 1.0 V at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C

#### PI74FCT162952T Features:

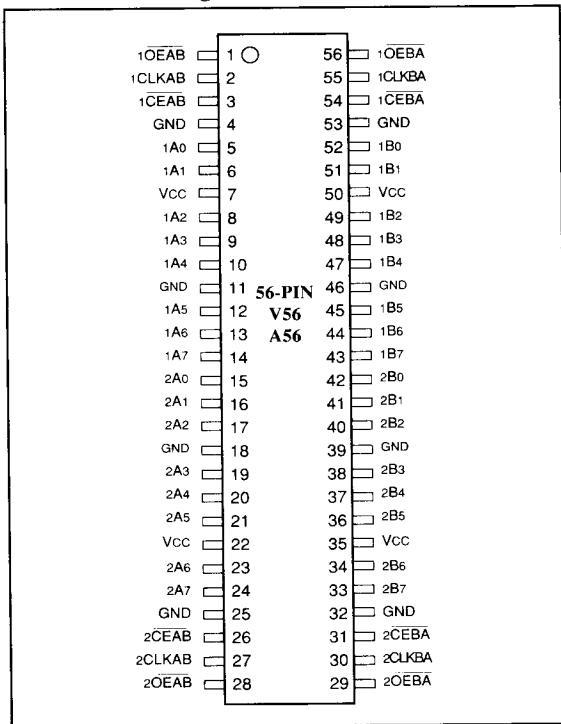
- Balanced output drivers: ±24 mA
- Reduced system switching noise
- Typical VOLP (Output Ground Bounce) < 0.6 V at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C

### Logic Block Diagram



**Product Pin Description**

Pin Name	Description
xOEAB	A-to-B Output Enable Input (Active LOW)
xOEBA	B-to-A Output Enable Input (Active LOW)
xCEAB	A-to-B Clock Enable Input (Active LOW)
xCEBA	B-to-A Clock Enable Input (Active LOW)
xCLKAB	A-to-B Clock Input
xCLKBA	B-to-A Clock Input
xAx	A-to-B Data Inputs or B-to-A 3-State Outputs
xBx	B-to-A Data Inputs or B-to-A 3-State Outputs
GND	Ground
Vcc	Power

**Product Pin Configuration**

**Truth Table<sup>(1,2)</sup>**

Inputs				Outputs
xCEAB	xCLKAB	xOEAB	xAx	xBx
H	X	L	X	B <sup>(3)</sup>
X	L	L	X	B <sup>(3)</sup>
L	↑	L	L	L
L	↑	L	H	H
X	X	H	X	High Z

**NOTES:**

1. H = High Voltage Level  
L = Low Voltage Level  
X = Don't Care or Irrelevant  
↑ = LOW-to-HIGH Transition  
Z = High Impedance
2. A-to-B data flow shown. B-to-A flow control is the same, except using xCEBA, xCLKBA, and xOEBA.
3. Level of B before the indicated steady-state input conditions were established.

**Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature .....	-55°C to +125°C
Ambient Temperature with Power Applied .....	-40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only) .....	-0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only) .....	-0.5V to Vcc
DC Input Voltage .....	-0.5V to +7.0V
DC Output Current .....	120 mA
Power Dissipation .....	1.0W

**Note:**

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

**DC Electrical Characteristics** (Over the Operating Range, TA = -40°C to +85°C, VCC = 5.0V ± 10%)

Parameters	Description	Test Conditions <sup>(1)</sup>	Min.	Typ <sup>(2)</sup>	Max.	Units
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0		V
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Logic LOW Level			0.8	V
I <sub>IH</sub>	Input HIGH Current	V <sub>CC</sub> = Max.	V <sub>IN</sub> = V <sub>CC</sub>		±5	µA
I <sub>IL</sub>	Input LOW Current	V <sub>CC</sub> = Max.	V <sub>IN</sub> = GND		±5	µA
I <sub>OZH</sub>	High Impedance	V <sub>CC</sub> = Max.	V <sub>OUT</sub> = 2.7 V		±10	µA
I <sub>OZL</sub>	Output Current	V <sub>CC</sub> = Max.	V <sub>OUT</sub> = 0.5 V		±10	µA
V <sub>IK</sub>	Clamp Diode Voltage	V <sub>CC</sub> = Min., I <sub>IN</sub> = -18 mA		-0.7	-1.2	V
I <sub>OS</sub>	Short Circuit Current	V <sub>CC</sub> = Max. <sup>(3)</sup> , V <sub>OUT</sub> = GND		-80	-140	mA
I <sub>O</sub>	Output Drive Current	V <sub>CC</sub> = Max. <sup>(3)</sup> , V <sub>OUT</sub> = 2.5 V		-50	-180	mA
V <sub>H</sub>	Input Hysteresis			100		mV

**PI74FCT16952T Output Drive Characteristics** (Over the Operating Range)

Parameters	Description	Test Conditions <sup>(1)</sup>	Min.	Typ <sup>(2)</sup>	Max.	Units	
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -3.0 mA	2.5	3.5	V	
			I <sub>OH</sub> = -15.0 mA	2.4	3.5		
			I <sub>OH</sub> = -32.0 mA	2.0	3.0		
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 64 mA		0.2	0.55	V
I <sub>OFF</sub>	Power Down Disable	V <sub>CC</sub> = 0 V, V <sub>IN</sub> or V <sub>OUT</sub> ≤ 4.5 V			±0.5	µA	

**PI74FCT162952T Output Drive Characteristics** (Over the Operating Range)

Parameters	Description	Test Conditions <sup>(1)</sup>	Min.	Typ <sup>(2)</sup>	Max.	Units	
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -24.0 mA	2.4	3.3	V	
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 24 mA		0.3	0.55	V
I <sub>ODL</sub>	Output LOW Current	V <sub>CC</sub> = 5 V, V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> , V <sub>OUT</sub> = 1.5 V <sup>(3)</sup>		60	115	150	mA
I <sub>ODH</sub>	Output HIGH Current	V <sub>CC</sub> = 5 V, V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> , V <sub>OUT</sub> = 1.5 V <sup>(3)</sup>		-60	-115	-150	mA

**Capacitance** (TA = 25°C, f = 1 MHz)

Parameters <sup>(4)</sup>	Description	Test Conditions	Typ	Max.	Units
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0 V	4.5	6	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0 V	5.5	8	pF

**Notes:**

- For conditions show as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at V<sub>CC</sub> = 5.0, +25°C ambient and maximum loading.
- Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- This parameter is determined by device characterization but is not production tested.

**Power Supply Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
I <sub>CC</sub>	Quiescent Power Supply Current	V <sub>CC</sub> = Max.	V <sub>IN</sub> = GND or V <sub>CC</sub>		2	500	μA
ΔI <sub>CC</sub>	Supply Current per Input @ TTL HIGH	V <sub>CC</sub> = Max.	V <sub>IN</sub> = 3.4 V <sup>(3)</sup>		0.5	1.5	mA
I <sub>CCD</sub>	Supply Current per Input per MHz <sup>(4)</sup>	V <sub>CC</sub> = Max., Outputs Open xOEAB or xOEBA = GND One Bit Toggling 50% Duty Cycle	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		75	120	μA/MHz
I <sub>C</sub>	Total Power Supply Current <sup>(6)</sup>	V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz (xCLKAB) 50% Duty Cycle xOEAB = xCEAB = GND xOEAB = V <sub>CC</sub> One Bit Toggling f <sub>I</sub> = 5 MHz 50% Duty Cycle	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		0.8	1.7 <sup>(5)</sup>	mA
		V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz (xCLKAB) 50% Duty Cycle xOEAB = xCEAB = GND xOEBA = V <sub>CC</sub> 16 Bits Toggling f <sub>I</sub> = 2.5 MHz 50% Duty cycle	V <sub>IN</sub> = 3.4 V V <sub>IN</sub> = GND		1.3	3.2 <sup>(5)</sup>	
		V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz (xCLKAB) 50% Duty Cycle xOEAB = xCEAB = GND xOEBA = V <sub>CC</sub> 16 Bits Toggling f <sub>I</sub> = 2.5 MHz 50% Duty cycle	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		3.4	5.9 <sup>(5)</sup>	
		V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz (xCLKAB) 50% Duty Cycle xOEAB = xCEAB = GND xOEBA = V <sub>CC</sub> 16 Bits Toggling f <sub>I</sub> = 2.5 MHz 50% Duty cycle	V <sub>IN</sub> = 3.4 V V <sub>IN</sub> = GND		7.6	18.7 <sup>(5)</sup>	

**Notes:**

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device.
2. Typical values are at V<sub>CC</sub> = 5.0 V, +25°C ambient.
3. Per TTL driven input (V<sub>IN</sub> = 3.4 V); all other inputs at V<sub>CC</sub> or GND.
4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
5. Values for these conditions are examples of the I<sub>CC</sub> formula. These limits are guaranteed but not tested.

6.  $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

$I_C = I_{CC} + \Delta I_{CC} D_{HNT} + I_{CCD} (f_{CP}/2 + f_I N_i)$

I<sub>CC</sub> = Quiescent Current

ΔI<sub>CC</sub> = Power Supply Current for a TTL High Input (V<sub>IN</sub> = 3.4 V)

D<sub>H</sub> = Duty Cycle for TTL Inputs High

N<sub>T</sub> = Number of TTL Inputs at D<sub>H</sub>

I<sub>CCD</sub> = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f<sub>CP</sub> = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f<sub>I</sub> = Input Frequency

N<sub>i</sub> = Number of Inputs at f<sub>I</sub>

All currents are in milliamps and all frequencies are in megahertz.

**PI74FCT16952T Switching Characteristics over Operating Range**

Preliminary

Parameters	Description	Conditions <sup>(1)</sup>	16952AT		16952BT		16952CT		16952DT		16952ET		Unit	
			Com.		Com.		Com.		Com.		Com.			
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
IPLH IPHL	Propagation Delay xCLKAB, xCLKBA to xBx, xAx	CL = 50 pF RL = 500	2.0	10.0	2.0	7.5	2.0	6.3	2.0	4.4	1.5	3.7	ns	
TPZH TPZL	Output Enable Time xOEBA, xOEAB to xAx, xBx		1.5	10.5	1.5	8.0	1.5	7.0	1.5	4.8	1.5	4.4	ns	
TPHZ TPLZ	Output Disable Time xOEBA, xOEAB to xAx, xBx		1.5	10.0	1.5	7.5	1.5	6.5	1.5	4.0	1.5	3.6	ns	
TSU	Set-up Time HIGH or LOW xAx, xBx to xCLKAB, xCLKBA		2.5	—	2.5	—	2.5	—	2.0	—	1.5	—	ns	
tH	Hold Time HIGH or LOW xAx, xBx to xCLKAB, xCLKBA		2.0	—	2.0	—	1.5	—	1.0	—	0.0	—	ns	
TSU	Set-up Time HIGH or LOW xCEAB, xCEBA to xCLKAB, xCLKBA		3.0	—	3.0	—	3.0	—	2.0	—	2.0	—	ns	
tH	Hold Time HIGH or LOW xCEAB, xCEBA to xCLKAB, xCLKBA		2.0	—	2.0	—	2.0	—	1.5	—	0.0	—	ns	
tw	Pulse Width HIGH <sup>(3)</sup> or LOW, xCLKAB or xCLKBA		3.0	—	3.0	—	3.0	—	3.0	—	3.0	—	ns	
tsk(o)	Output Skew <sup>(3)</sup>		—	0.5	—	0.5	—	0.5	—	0.5	—	0.5	ns	

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**PI74FCT162952T Switching Characteristics over Operating Range**

Preliminary

Parameters	Description	Conditions <sup>(1)</sup>	162952AT		162952BT		162952CT		162952DT		162952ET		Unit	
			Com.		Com.		Com.		Com.		Com.			
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
IPLH IPHL	Propagation Delay xCLKAB, xCLKBA to xBx, xAx	CL = 50 pF RL = 500	2.0	10.0	2.0	7.5	2.0	6.3	2.0	4.4	1.5	3.7	ns	
TPZH TPZL	Output Enable Time xOEBA, xOEAB to xAx, xBx		1.5	10.5	1.5	8.0	1.5	7.0	1.5	4.8	1.5	4.4	ns	
TPHZ TPLZ	Output Disable Time xOEBA, xOEAB to xAx, xBx		1.5	10.0	1.5	7.5	1.5	6.5	1.5	4.0	1.5	3.6	ns	
TSU	Set-up Time HIGH or LOW xAx, xBx to xCLKAB, xCLKBA		2.5	—	2.5	—	2.5	—	2.0	—	1.5	—	ns	
tH	Hold Time HIGH or LOW xAx, xBx to xCLKAB, xCLKBA		2.0	—	2.0	—	1.5	—	1.0	—	0.0	—	ns	
TSU	Set-up Time HIGH or LOW xCEAB, xCEBA to xCLKAB, xCLKBA		3.0	—	3.0	—	3.0	—	2.0	—	2.0	—	ns	
tH	Hold Time HIGH or LOW xCEAB, xCEBA to xCLKAB, xCLKBA		2.0	—	2.0	—	2.0	—	1.5	—	0.0	—	ns	
tw	Pulse Width HIGH <sup>(3)</sup> or LOW, xCLKAB or xCLKBA		3.0	—	3.0	—	3.0	—	3.0	—	3.0	—	ns	
tsk(o)	Output Skew <sup>(3)</sup>		—	0.5	—	0.5	—	0.5	—	0.5	—	0.5	ns	

**Notes:**

- See test circuit and wave forms.
- Minimum limits are guaranteed but not tested on Propagation Delays.
- Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.